## NSN 5961-01-356-9296

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-356-9296 **Inclosure Material:** Glass **Overall Length:** Between 0.026 inches and 0.030 inches **Overall Width:** Between 0.006 inches and 0.010 inches **Function For Which Designed:** Detector **Mounting Method:** Press fit **Criticality Code Justification:** Feat **Voltage Rating In Volts Per Characteristic:** 4.0 breakdown voltage, instantaneous **Power Rating Per Characteristic:** 150.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Hardness critical process; junction pattern arrangement: pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

Yes - demil/mli

**Fiig:** A110a0